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2021.12.22

ALL

6DM

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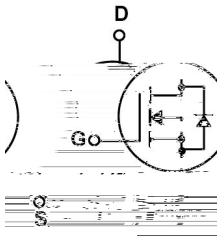


TO-263 N
N-CHANNEL MOSFET in a TO-263 Plastic Package.

Ultra Low On-Resistance,fast switching,Halogen-free Product.

PFC

These devices are well suited for high efficient switched mode power supplies, Active power factor correction, electronic lamp ballast based on half bridge topology.



PIN1 G PIN 2 4 D PIN 3 S

See Marking Instructions.



Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	60	V
Drain Current	$I_D(T_c=25^\circ C)$	140	A



Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Total Gate Charge	$Q_g(10V)$	$V_{GS}=10V$ $V_{DS}=30V$ $I_D=20A$		60		nC
Total Gate Charge	$Q_g(4.5V)$			23		
Gate Source Charge	Q_{gs}			16		
Gate Drain Charge	Q_{gd}			3		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1$ $R_{GEN}=3$		13		ns
Turn-On Rise Time	t_r			4		

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